Analog Power AM40N10-30D

N-Channel 100-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

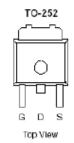
Typical Applications:

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- · White LED boost converters

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)		
100	36 @ V _{GS} = 10V	26		
	$42 @ V_{GS} = 4.5V$	24		







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage		V_{DS}	100	V		
Gate-Source Voltage		V_{GS}	±20	V		
Continuous Drain Current	T _C =25°C	I _D	26	Α		
Pulsed Drain Current ^b		I _{DM}	50	Α		
Continuous Source Current (Diode Conduction)			50	Α		
Power Dissipation	T _C =25°C	P_{D}	50	W		
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 175	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	50	°C/W		
Maximum Junction-to-Case	$R_{\theta JC}$	3	C/VV		

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Typical Electrical Characteristics

Parameter	Symbol	Symbol Test Conditions		Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $ID = 250 \text{ uA}$	1		3.5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$	V		1	uA	
	I _{DSS}	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	34			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$			36	mΩ	
Dialii-Source Oil-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 9.2 \text{ A}$			42		
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ A}$		10		S	
Diode Forward Voltage	V_{SD}	$I_{S} = 25 \text{ A}, V_{GS} = 0 \text{ V}$		0.89		V	
		Dynamic					
Total Gate Charge	Q_g			14.8			
Gate-Source Charge	Q_gs	$V_{DS} = 50 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 10 \text{ A}$		4.3		nC	
Gate-Drain Charge	Q_gd			8.6]	
Turn-On Delay Time	t _{d(on)}			4.8			
Rise Time	t _r	V_{DD} = 50 V, R_L = 5 Ω , I_D = 10 A,		14.2		nS	
Turn-Off Delay Time	$t_{d(off)}$	V_{GEN} = 10 V, R_{GEN} = 6 Ω		39.2			
Fall Time	t _f			25.6			
Input Capacitance	C _{iss}			1216			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		154		pF	
Reverse Transfer Capacitance	C_{rss}			131			

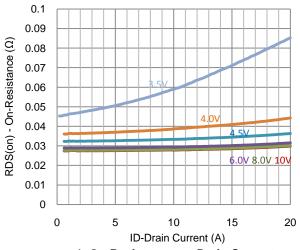
Notes

- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

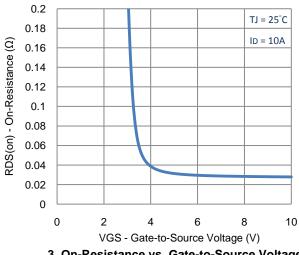
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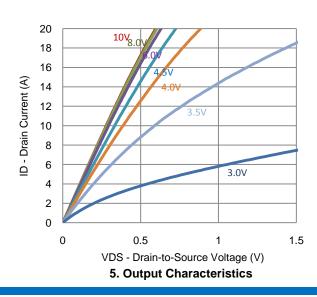
Typical Electrical Characteristics

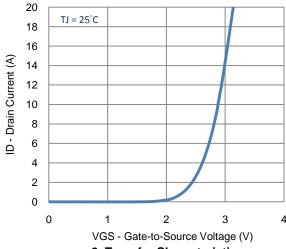


1. On-Resistance vs. Drain Current

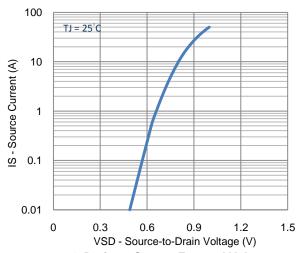


3. On-Resistance vs. Gate-to-Source Voltage

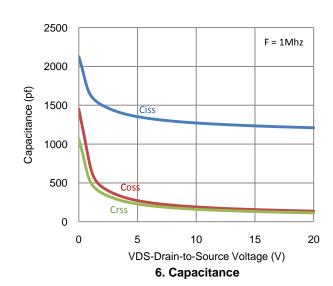




2. Transfer Characteristics

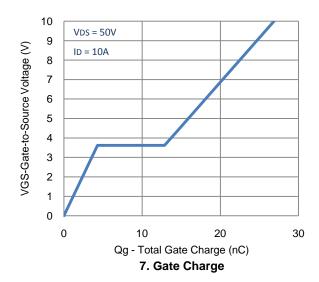


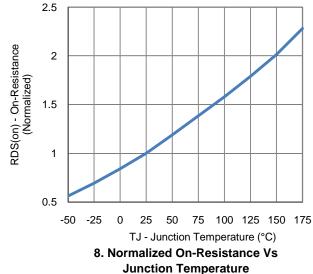
4. Drain-to-Source Forward Voltage

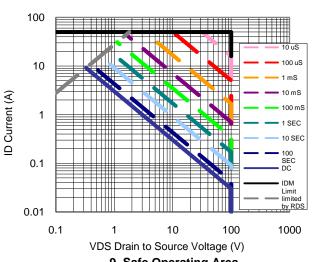


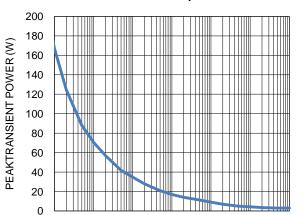
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Typical Electrical Characteristics









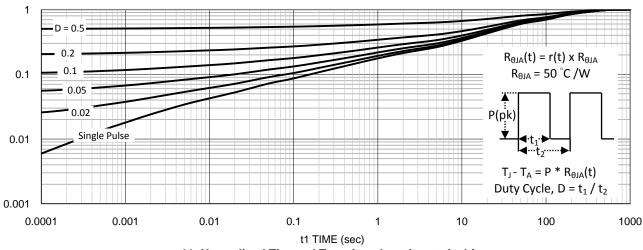


t1 TIME (SEC) 10. Single Pulse Maximum Power Dissipation

10

100

1000



0.001

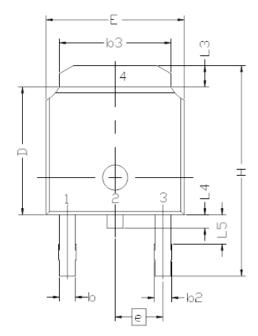
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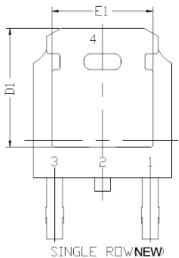
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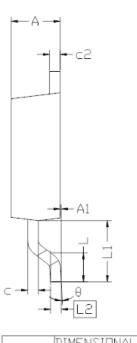
11. Normalized Thermal Transient Junction to Ambient

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Package Information







CVMDDI	DIMENS:	IDNAL F	REQMTS
SYMBOL	MIN	NDM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1		.743 RI	
L2	0.	.508 BS	
_L3	0.89		1.27
L4	0.64		1.01
L5			
D	6.00	6.10	6,223
Н	9.40	10.00	10.40
b	0.64	0.76	0,88
b2	0.77	0.84	1.14
b3	5.21	5.34	5,46
е	2.	286 BS	Č
e A	2,20	2.30	2,38
A1	0		0.127
C	0.45	0.50	0.60
c2	0.45	0.50	0.58
D1	5,30		
E1	4.40		
θ	0°		10°

Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.